

ZL10100 Single Chip Synthesized Downconverter with IF Amplifier Data Sheet

April 2005

Features

- Single chip synthesised downconverter forming a complete double conversion tuner when combined with the SL2100 or SL2101
- Compatible with digital and analogue system requirements
- CTB contribution < -64 dBc, CXM contribution
 < -62 dBc and spectral spread < -64 dBc
- IF amplifier optimized to interface with standard SAW filters
- Extremely low phase noise balanced local oscillator, with very low fundamental and harmonic radiation
- PLL frequency synthesizer designed for high comparison frequencies and low phase noise
- Available in 28 pin SSOP and MLP packages

Applications

- Double conversion tuners
- Digital Terrestrial tuners
- Cable Modems
- · Cable telephony
- MATV

| - | | | | | | | | | | | |
|---|--|---|---|--|--|--|--|--|--|--|--|
| | Ordering Information | | | | | | | | | | |
| | ZL10100/DDE ZL10100/DDF ZL10100/DDE1 ZL10100/DDF1 ZL10100/LDG1 ZL10100/LDF1 | SSOP SSOP* SSOP* SSOP* MLP* MLP* | Tubes Tape & Reel, Tubes Tape & Reel Trays Tape & Reel | | | | | | | | |
| | * Pb free | | | | | | | | | | |
| | All codes Baked an Drypacked | | | | | | | | | | |
| | -40°C | C to +85°C | | | | | | | | | |

Description

The ZL10100 is a fully integrated single chip mixer oscillator with on-board low phase noise I2C bus controlled PLL frequency synthesizer. It is intended primarily as the down converter for application in double conversion tuners and is compatible with HIIF frequencies between 1 and 1.3 GHz and all standard tuner IF output frequencies.

The device contains all elements necessary, with the exception of local oscillator tuning network, loop filter and crystal reference to fabricate a complete synthesized block converter with IF amplifier, compatible with digital and analogue requirements.

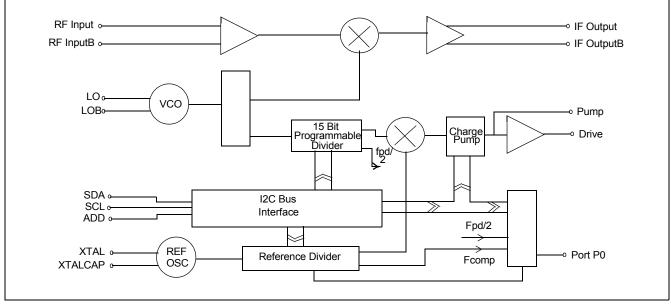
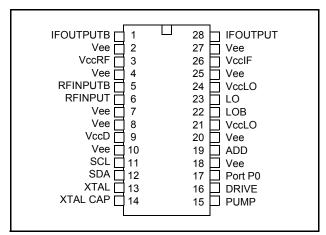


Figure 1 - ZL10100 Functional Block Diagram

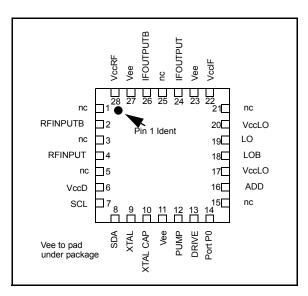
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Pin Description









Quick Reference Data

All data applies with the following conditions unless otherwise stated;

- a) Output load of 150 Ω , differential
- b) Input spectrum of 5 channels centred on 1220 MHz, each carrier @ 77 $dB\mu V$

| Characteristic | | Units |
|---|----------------|------------------|
| RF input operating range | 1-1.3 | GHz |
| IF output operating range | 30-60 | MHz |
| Input noise figure, SSB | 9 | dB |
| Conversion gain, diff to diff | 24 | dB |
| СТВ | < -66 | dBc |
| СХМ | < -63 | dBc |
| Spectral spread | <-70 | dBc |
| Local oscillator phase noise SSB @ 10 kHz offset SSB @ 100 kHz offset | c -93 c-115 | dBc/Hz dBc/Hz |
| Local oscillator phase noise floor | -136 | dBc/Hz |
| IF output impedance, differential | 150 | Ω |
| PLL phase noise at phase detector, 1 MHz comparison frequency | -152 | dBc/Hz |

1.0 Functional Description

The ZL10100 is a bipolar, broadband wide dynamic range mixer oscillator with on-board I2C bus controlled PLL frequency synthesizer, optimized for application as the down converter in double conversion tuner systems. It also has application in any system where a wide dynamic range broadband synthesized frequency converter is required.

The ZL10100 is a single chip solution containing all necessary active circuitry and simply requires an external tuneable resonant network for the local oscillator sustaining network. The pin assignment is contained in the block diagram in Figure 1 and the Pin Description in Figure 2.

1.1 Converter Section

In normal application the HIIF input is interfaced through appropriate impedance matching to the device input. The RF input preamplifier of the device is designed for low noise figure, within the operating region of 1 to 1.3 GHz and for high intermodulation distortion intercept so offering good signal to noise plus composite distortion spurious performance when loaded with a multi carrier system. The preamplifier also provides gain to the mixer section and back isolation from the local oscillator section. The typical RF input impedance and matching network for matching to a 1220 MHz HIIF filter, type B1603 are contained in Figures 3 and 4.

The output of the preamplifier is fed to the mixer section which is optimized for low radiation application. In this stage the RF signal is mixed with the local oscillator frequency, which is generated by the on-board oscillator. The oscillator block uses an external tuneable network and is optimized for low phase noise. The typical application is shown in Figure 6, and the phase noise performance in Figure 7. This block interfaces direct with the internal PLL to allow for frequency synthesis of the local oscillator.

The output of the mixer is internally coupled to a differential IF amplifier, which provides further gain and provides for a 150 Ω , differential output impedance and drive capability. The IF amplifier allows for IF frequencies between 30 and 60 MHz.

The typical IF output impedance is contained in Figure 8.

The typical key performance data at 5 V Vcc and 25 deg C ambient are shown in the Quick Reference Data section on Page 2.

1.2 Local Oscillator

To maximize the local oscillator phase noise performance, the application circuit as in Figure 5 must be carefully adhered to including the component type and manufacture where applicable, strip line dimension and board material. Any deviation from these parameters may adversely affect phase noise characteristics and so will require re-optimization.

1.3 PLL frequency Synthesizer

The PLL frequency synthesizer section contains all the elements necessary, with the exception of a reference frequency source and loop filter to control the oscillator, so forming a complete PLL frequency synthesized source. The device allows for operation with a high comparison frequency and is fabricated in high speed logic, which enables the generation of a loop with good phase noise performance.

The LO signal from the oscillator drives an internal preamplifier, which provides gain and reverse isolation from the divider signals. The output of the preamplifier interfaces direct with the 15-bit fully programmable divider. The programmable divider is of MN+A architecture, where the dual modulus prescaler is 16/17, the A counter is 4-bits, and the M counter is 11 bits.

The output of the programmable divider is fed to the phase comparator where it is compared in both phase and frequency domain with the comparison frequency. This frequency is derived either from the on-board crystal controlled oscillator or from an external reference source. In both cases the reference frequency is divided down to the comparison frequency by the reference divider which is programmable into 1 of 29 ratios as detailed in Table 1.

The typical application for the crystal oscillator is contained in Figure 9 which also demonstrates how a 4 MHz reference signal can be coupled out to a further PLL frequency synthesizer, such as the upconverter section in a double conversion tuner.

The output of the phase detector feeds a charge pump and loop amplifier, which when used with an external loop filter and high voltage transistor, integrates the current pulses into the varactor line voltage, used for controlling the oscillator.

The programmable divider output Fpd divided by two and the reference divider output Fcomp can be switched to port P0 by programming the device into test mode. The test modes are described in Table 2.

2.0 Programming

The ZL10100 is controlled by an I2C data bus and is compatible with both standard and fast mode formats.

Data and Clock are fed in on the SDA and SCL lines respectively as defined by I2C bus format. The device can either accept data (write mode), or send data (read mode). The LSB of the address byte (R/W) sets the device into write mode if it is low, and read mode if it is high. Tables 3, 4 and 5 illustrate the format of the data. The device can be programmed to respond to several addresses, which enables the use of more than one device in an I2C bus system. Table 5 shows how the address is selected by applying a voltage to the 'ADD' input. When the device receives a valid address byte, it pulls the SDA line low during the acknowledge period, and during following acknowledge periods after further data bytes are received. When the device is programmed into read mode, the controller accepting the data must pull the SDA line low during all status byte acknowledge periods to read another status byte. If the controller fails to pull the SDA line low during this period, the device generates an internal STOP condition, which inhibits further reading.

2.1 Write Mode

With reference to Table 5, bytes 2 and 3 contain frequency information bits 214-20 inclusive. Byte 4 controls the synthesizer reference divider ratio, see Table 1 and the charge pump setting, see Table 6. Byte 5 controls the test modes, see Table 2 and the output port P0.

After reception and acknowledgement of a correct address (byte 1), the first bit of the following byte determines whether the byte is interpreted as a byte 2 or 4, a logic '0' indicating byte 2, and a logic '1' indicating byte 4. Having interpreted this byte as either byte 2 or 4 the following data byte will be interpreted as byte 3 or 5 respectively. Having received two complete data bytes, additional data bytes can be entered, where byte interpretation follows the same procedure, without re-addressing the device. This procedure continues until a STOP condition is received. The STOP condition can be generated after any data byte, if however it occurs during a byte transmission, the previous byte data is retained. To facilitate smooth fine tuning, the frequency data bytes are only accepted by the device after all 15 bits of frequency data have been received, or after the generation of a STOP condition.

2.2 Read Mode

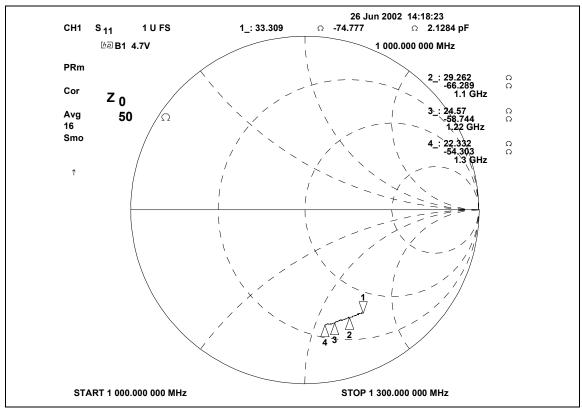
When the device is in read mode, the status byte read from the device takes the form shown in Table 4.

Bit 1 (POR) is the power-on reset indicator, and this is set to a logic '1' if the Vcc supply to the device has dropped below 3 V (at 25°C), e.g., when the device is initially turned ON. The POR is reset to '0' when the read sequence is terminated by a STOP command. When POR is set high this indicates that the programmed information may have been corrupted and the device reset to the power up condition.

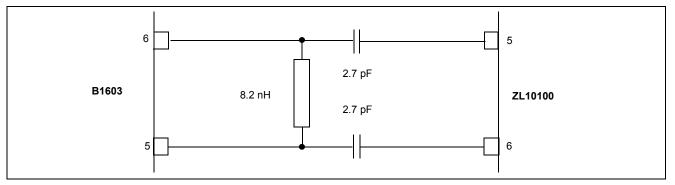
Bit 2 (FL) indicates whether the synthesizer is phase locked, a logic '1' is present if the device is locked, and a logic '0' if the device is unlocked.

Programmable Features

| Synthesizer programmable divider | Function as described above. |
|----------------------------------|--|
| Reference programmable divider | Function as described above. |
| Charge pump current | The charge pump current can be programmed by bits C1 and C0 within data byte 4, as defined in Table 6. |
| Test mode | The test modes are defined by bits T2-T0 as described in Table 2. |
| General purpose ports, P0 | The general purpose port can be programmed by bits P0; Logic '1' = on Logic '0' = off (high impedance) |









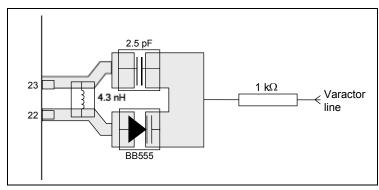


Figure 6 - Oscillator Application

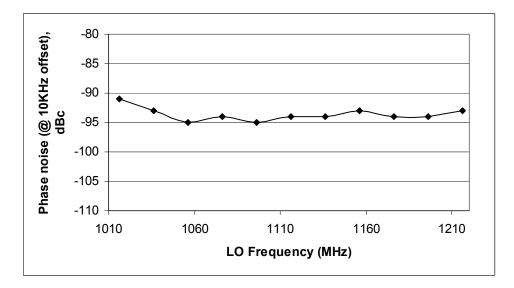


Figure 7 - Typical Phase Noise Performance with Application as in Figure 6

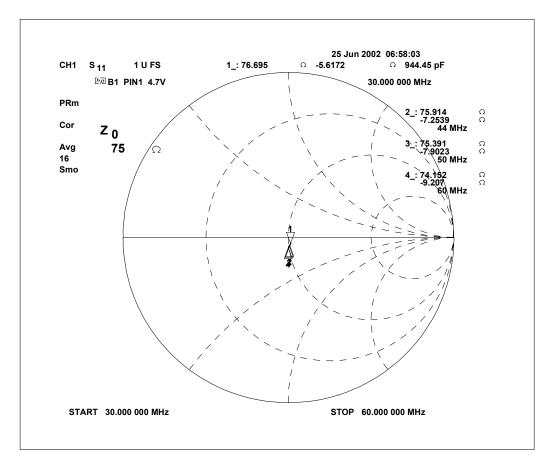


Figure 8 - Typical IF Output Impedance Single-Ended

| R4 | R3 | R2 | R1 | R0 | Ratio |
|----|----|----|----|----|---------------|
| 0 | 0 | 0 | 0 | 0 | 2 |
| 0 | 0 | 0 | 0 | 1 | 4 |
| 0 | 0 | 0 | 1 | 0 | 8 |
| 0 | 0 | 0 | 1 | 1 | 16 |
| 0 | 0 | 1 | 0 | 0 | 32 |
| 0 | 0 | 1 | 0 | 1 | 64 |
| 0 | 0 | 1 | 1 | 0 | 128 |
| 0 | 0 | 1 | 1 | 1 | 256 |
| 0 | 1 | 0 | 0 | 0 | Illegal state |
| 0 | 1 | 0 | 0 | 1 | 5 |
| 0 | 1 | 0 | 1 | 0 | 10 |
| 0 | 1 | 0 | 1 | 1 | 20 |
| 0 | 1 | 1 | 0 | 0 | 40 |
| 0 | 1 | 1 | 0 | 1 | 80 |
| 0 | 1 | 1 | 1 | 0 | 160 |
| 0 | 1 | 1 | 1 | 1 | 320 |
| 1 | 0 | 0 | 0 | 0 | Illegal state |
| 1 | 0 | 0 | 0 | 1 | 6 |
| 1 | 0 | 0 | 1 | 0 | 12 |
| 1 | 0 | 0 | 1 | 1 | 24 |
| 1 | 0 | 1 | 0 | 0 | 48 |
| 1 | 0 | 1 | 0 | 1 | 96 |
| 1 | 0 | 1 | 1 | 0 | 192 |
| 1 | 0 | 1 | 1 | 1 | 384 |
| 1 | 1 | 0 | 0 | 0 | Illegal state |
| 1 | 1 | 0 | 0 | 1 | 7 |
| 1 | 1 | 0 | 1 | 0 | 14 |
| 1 | 1 | 0 | 1 | 1 | 28 |
| 1 | 1 | 1 | 0 | 0 | 56 |
| 1 | 1 | 1 | 0 | 1 | 112 |
| 1 | 1 | 1 | 1 | 0 | 224 |
| 1 | 1 | 1 | 1 | 1 | 448 |

Table 1 - Reference Division Ratios

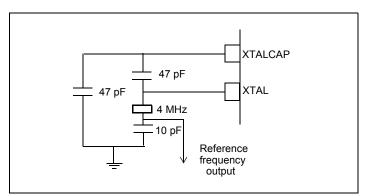


Figure 9 - Crystal Oscillator Application

| T2 | T1 | Т0 | Test Mode Description |
|----|----|----|---|
| 0 | 0 | 0 | Normal operation |
| 0 | 0 | 1 | Charge pump sink* Status byte FL set to logic '0' |
| 0 | 1 | 0 | Charge pump source* Status byte FL set to logic '0' |
| 0 | 1 | 1 | Charge pump disabled* Status byte FL set to logic '1' |
| 1 | 0 | 0 | Normal operation and Port P0 = Fpd/2 |
| 1 | 0 | 0 | Charge pump sink* Status byte FL set to logic '0' Port P0 = Fcomp |
| 1 | 1 | 0 | Charge pump source* Status byte FL set to logic '0' Port P0 = Fcomp |
| 1 | 1 | 1 | Charge pump disabled* Status byte FL set to logic '1' Port P0 = Fcomp |

Table 2 - Test Modes

* clocks need to be present on crystal and local oscillator to enable charge pump test modes and to toggle status byte bit FL

| | MSB | | | | | | | LSB | | |
|----------------------|------------|-----------------|-----------------|-----------------|-----------------|-----------------|----------------|----------------|---|--------|
| Address | 1 | 1 | 0 | 0 | 0 | MA1 | MA0 | 0 | Α | Byte 1 |
| Programmable divider | 0 | 2 ¹⁴ | 2 ¹³ | 2 ¹² | 2 ¹¹ | 2 ¹⁰ | 2 ⁹ | 2 ⁸ | Α | Byte 2 |
| Programmable divider | 27 | 2 ⁶ | 2 ⁵ | 2 ⁴ | 2 ³ | 2 ² | 2 ¹ | 2 ⁰ | Α | Byte 3 |
| Control data | 1 | C1 | C0 | R4 | R3 | R2 | R1 | R0 | Α | Byte 4 |
| Control data | T2 | T1 | T0 | Х | Х | Х | 0 | P0 | Α | Byte 5 |
| T- | ala 2 \A/# | | | -+ /> | | | 44 a. d. 🗖 : | | | |

Table 3 - Write Data Format (MSB is Transmitted First)

| | MSB | | | | | | | LSB | | |
|-------------|-----|----|---|---|---|-----|-----|-----|---|--------|
| Address | 1 | 1 | 0 | 0 | 0 | MA1 | MA0 | 1 | Α | Byte 1 |
| Status Byte | POR | FL | 0 | 0 | 0 | 0 | 0 | 0 | Α | Byte 2 |

Table 4 - Read Data Format (MSB is Transmitted First)

: Acknowledge bit А MA1,MA0 : Variable address bits (see Table 5) 2¹⁴-2⁰ : Programmable division ratio control bits C1-C0 : Charge pump current select (see Table 6) R4-R0 : Reference division ratio select (see Table 1) T2-T0 Test mode control bits (see Table 2) : P0 P0 port output state : POR Power on reset indicator 1 Phase lock flag FL 1 Х 'Don't care' :

| MA1 | MA0 | Address Input Voltage Level | | | | | | |
|-----|-----------------------------|-----------------------------|--|--|--|--|--|--|
| 0 | 0 | 0-0.1 Vcc | | | | | | |
| 0 | 1 | Open circuit | | | | | | |
| 1 | | 0.4Vcc - 0.6 Vcc # | | | | | | |
| 1 | 1 | 0.9 Vcc - Vcc | | | | | | |
| L | Table 5 - Address Selection | | | | | | | |

Programmed by connecting a 30 $k\Omega$ resistor between pin and Vcc

| C1 | C0 | Current in μ A | | | | | | | |
|----|----|--------------------|--------|--------|--|--|--|--|--|
| | 00 | Min. | Тур. | Max. | | | | | |
| 0 | 0 | ± 98 | ± 130 | ± 162 | | | | | |
| 0 | 1 | ± 210 | ± 280 | ± 350 | | | | | |
| 1 | 0 | ± 450 | ± 600 | ± 750 | | | | | |
| 1 | 1 | ± 975 | ± 1300 | ± 1625 | | | | | |

Table 6 - Charge Pump Current

Electrical Characteristics - Test conditions (unless otherwise stated) T_{amb} = -40°C to 85°C, Vee = 0 V, Vcc = 5 V±5%. Input frequency 1220 MHz. IF output frequency 44 MHz.

These characteristics are guaranteed by either production test or design. They apply within the specified ambient temperature and supply voltage unless otherwise stated.

| Characteristic | Pin | Min. | Тур. | Max. | Units | Conditions |
|--|-----|------|-------------|-------------|------------------|--|
| Supply current | | | 120 | 160 | mA | |
| Input frequency range | | 1 | | 1.3 | GHz | |
| Composite peak input signal | | | 86 | | dBμV | Operating condition only. |
| Input impedance | | | | | | See Figure 4. |
| Input Noise Figure | | | 9 | 11 | dB | Tamb = 27°C |
| Conversion gain | | 20 | 23 | 26 | dB | Differential to differential voltage gain to differential 150 Ω load. |
| Gain variation within channel | | | | 0.5 | dB | Channel bandwidth 8 MHz within operating frequency range. |
| Through gain | | | | -30 | dB | |
| СТВ | | | | -64 | dBc | See note 4. |
| CXM | | | | -62 | dBc | See note 4. |
| LO operating range | | 0.9 | | 1.6 | GHz | Maximum tuning range determined by application, see note (3), guaranteed by design. |
| LO phase noise, SSB @ 10 kHz offset @ 100 kHz offset | | | -94 -116 | -90 -110 | dBc/Hz dBc/Hz | See Figure 7. Application as in Figure 6. |
| LO phase noise floor | | | | -136 | dBc/Hz | Application as in Figure 6. |
| IF output frequency range | | 30 | | 60 | MHz | |
| IF output impedance | | | 75 | | Ω | Single-ended. See Figure 8. |
| IF output return loss | | | | -20 | dB | See Figure 8, over operating range. |
| All other spurs on IF Output | | | | 20 | dBμV | Within channel bandwidth of 8 MHz. |

Electrical Characteristics - Test conditions (unless otherwise stated)

 T_{amb} = -40°C to 85°C, Vee = 0 V, Vcc = 5 V±5%. Input frequency 1220 MHz. IF output frequency 44 MHz.

These characteristics are guaranteed by either production test or design. They apply within the specified ambient temperature and supply voltage unless otherwise stated.

| Characteristic | Pin | Min. | Тур. | Max. | Units | Conditions |
|---|-----|---------------|--------------|------------------------|-------------------------|--|
| SYNTHESIZER | | | | | 1 | |
| SDA, SCL Input high voltage Input low voltage Input high current Input low current Leakage current Hysterysis | | 3 0 -10 | 0.4 | 5.5 1.5 10 10 | V V μΑ μΑ V | I2C 'Fast mode' compliant Input voltage = Vcc Input voltage = Vee Vcc = Vee |
| SDA output voltage | | | | 0.4 0.6 | V V | Isink = 3 mA Isink = 6 mA |
| SCL clock rate | | | | 400 | kHz | |
| Charge pump output current | | | ±3 | ±10 | nA | See Table 6. Vpin = 2 V |
| Charge pump drive output current | | 0.5 | | | mA | Vpin = 0.7 V |
| Crystal frequency | | 2 | | 20 | MHz | See Figure 9 for application. |
| Recommended crystal series resistance | | 10 | | 200 | Ω | 4 MHz parallel resonant crystal |
| External reference input frequency | | 2 | | 20 | MHz | Sinewave coupled through 10 nF blocking capacitor |
| External reference drive level | | 0.2 | | 0.5 | Vpp | Sinewave coupled through 10 nF blocking capacitor |
| Phase detector comparison frequency | | | | 4 | MHz | |
| Equivalent phase noise at phase detector | | | -152 -158 | | dBc/Hz dBc/Hz | SSB, within loop bandwidth 2 MHz 250 kHz |
| Local oscillator programmable divider division ratio | | 240 | | 32767 | | |
| Reference division ratio | | | | | | See Table 1. |
| Output port sink current leakage current | | 2 | | 10 | mA μA | See note 2. Vport = 0.7 Vport = Vcc |
| Address select Input high current Input low current | | | | 1 -0.5 | mA mA | See Table 5 Vin = Vcc Vin = Vee |

Notes

(1) When measuring from a 50 Ω environment, the voltage step up transformation needs to be taken into account.

(2) Port powers up in high impedance state.

(3) To maximize phase noise the tuning range should be minimised and Q of resonator maximized. The application as in Figure 6 has a tuning range of 200 MHz.

(4) Measured with 5 channels @ 77 dBuV centred on desired channel.

| Characteristic | Min. | Max. | Units | Conditions |
|--|------|---------|-------|-------------------------------|
| Supply voltage | -0.3 | 7 | V | |
| RF input voltage | | 117 | dBuV | Differential |
| All I/O port DC offsets | -0.3 | Vcc+0.3 | V | |
| SDA, SCL DC offsets | -0.3 | 6 | V | Vcc = Vee to 5.25 V |
| Storage temperature | -55 | 150 | °C | |
| Junction temperature | | 150 | °C | |
| Package thermal resistance, chip to case | | 20 | °C/W | |
| Package thermal resistance, chip to case | | 80 | °C/W | |
| Power consumption at 5.25 V | | 700 | mW | |
| ESD protection | 3.5 | | kV | Mil-std 883B method 3015 cat1 |

Absolute Maximum Ratings - All voltages are referred to Vee at 0 V.

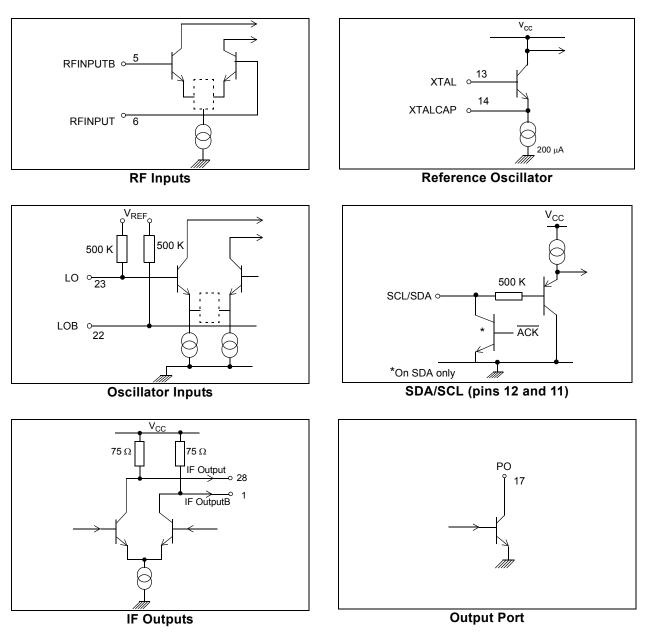


Figure 10 - Input and Output Interface Circuits

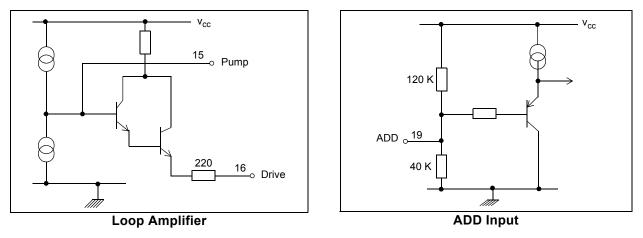
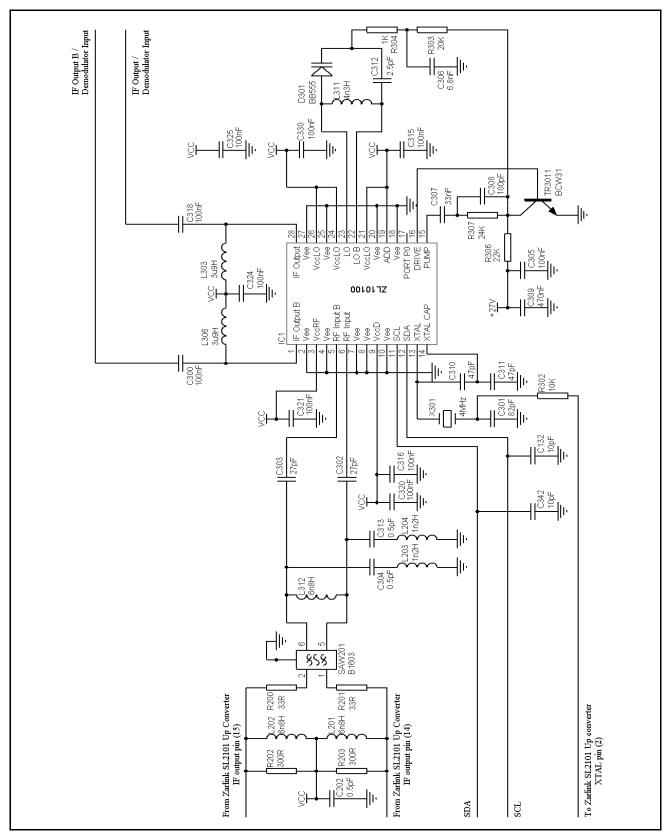
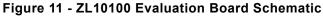
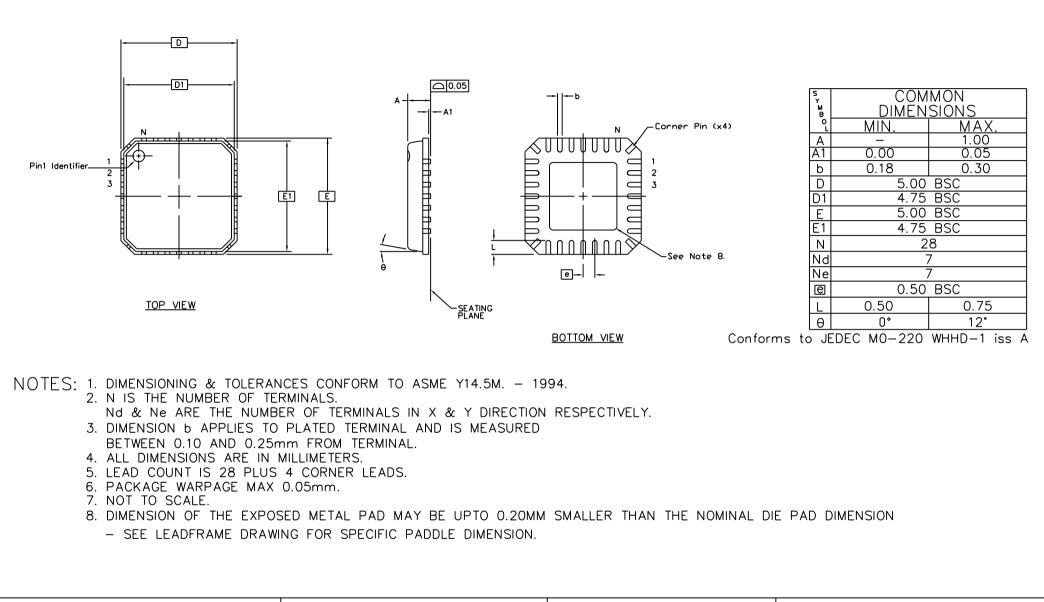


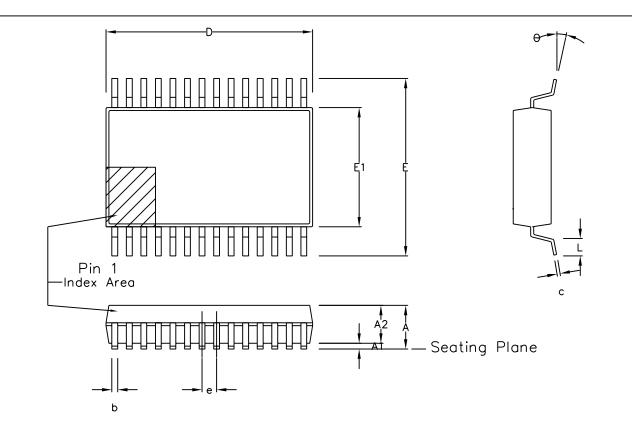
Figure 10 - Input and Output Interface Circuits







| © Zarlink Semiconductor 2003 All rights reserved. | | | | | | | Package Code | |
|---|---------|---------|--------|---------|--|---------------------------------|------------------------|-----------------------------|
| ISSUE | 2 | 3 | 4 | 5 | | | Previous package codes | Package Outline for Stamped |
| ACN | 208382 | 208538 | 212490 | CDCA | | ZARLINK SEMICONDUCTOR | LH | 28 (+4) Lead QFN (5x5mm) |
| DATE | 17Feb00 | 16Mar00 | 8Apr02 | 17Dec03 | | SEMICONDUCTOR | | |
| APPRD. | | | | | | | | GPD00632 |



| Symbol | | ol Dimer millimet | | | Altern. Dimensions in inches | | | |
|------------------------------------|--------------|----------------------|-------|--|---------------------------------|---------|--------|--|
| Symbol | MIN | Nominal | | | MIN | Nominal | | |
| Α | 1.70 | | 2.00 | | 0.067 | | 0.079 | |
| A1 | 0.05 | | 0.20 | | 0.002 | | 0.008 | |
| A2 | 1.65 | | 1.85 | | 0.065 | | 0.073 | |
| D | 9.90 | | 10.50 | | 0.390 | | 0.413 | |
| E | 7.40 | | 8.20 | | 0.291 | | 0.323 | |
| E1 | 5.00 | | 5.60 | | 0.197 | | 0.220 | |
| L | 0.55 | | 0.95 | | 0.022 | | 0.037 | |
| е | 0.65 BSC. | | | | 0.026 BSC. | | | |
| b | 0.22 | | 0.38 | | 0.009 | | 0.015 | |
| С | 0.09 | | 0.25 | | 0.004 | | 0.010 | |
| Θ | 0° | | 8' | | 0° | | ° 8 | |
| | Pin features | | | | | | | |
| Ν | 28 | | | | | | | |
| Conforms to JEDEC MO-150 AH Iss. B | | | | | | | | |

This drawing supersedes: -418/ED/51481/004 (Swindon/Plymouth)

Notes:

- 1. A visual index feature, e.g. a dot, must be located within the cross-hatched area.
- 2. Controlling dimension are in millimeters.
- 3. Dimensions D and E1 do not include mould flash or protusion. Mould flash or protusion shall not exceed
- 0.20 mm per side. D and E1 are maximum plastic body size dimensions including mould mismatch.
 4. Dimension b does not include dambar protusion/intrusion. Allowable dambar protusion shall be 0.13 mm total in excess of b dimension. Dambar intrusion shall not reduce dimension b by more than 0.07 mm.

| © Zarlink Semiconductor 2002 All rights reserved. | | | | | | Package Code |
|---|---------|---------|--------|--|------------------------|--|
| ISSUE | 1 | 2 | 3 | | Previous package codes | Package Outline for 28 lead SSOP (5.3mm Body Width) |
| ACN | 201935 | 205232 | 212478 | | | |
| DATE | 27Feb97 | 25Sep98 | 3Apr02 | | | |
| APPRD. | | | | | | GPD00296 |



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